MAX.

800E

800F

800

12

95

UNIT

V

А

А

Three quadrant triacs guaranteed commutation

BTA212B series D, E and F

MAX.

600D

600E

600F

600

12

95

GENERAL DESCRIPTION

Passivated guaranteed commutation triacs in a plastic envelope suitable for surface mounting intended for use in motor control circuits or with other highly inductive loads. These devices balance the requirements of commutation performance and gate sensitivity. The 'sensitive gate" E series and "logic level" D series are intended for interfacing with low power drivers, including micro controllers.

PINNING - SOT404

main terminal 1

main terminal 2

main terminal 2

PIN

1

2

3

mb

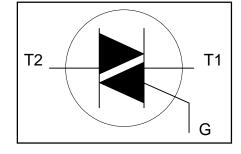
DESCRIPTION

SYMBOL

BTA212B-

BTA212B-

BTA212B-



LIMITING VALUES

gate

Limiting values in accordance with the Absolute Maximum System (IEC 134).

| SYMBOL | PARAMETER | CONDITIONS | MIN. | MAX. | | UNIT |
|---|---|--|----------|---------------------------------|--------------------|--------------------------|
| V _{drm} | Repetitive peak off-state voltages | | - | -600 600 ¹ | -800 800 | V |
| I _{T(RMS)} | RMS on-state current | full sine wave; $T_{mb} \le 99 \degree C$ | - [| 12 | 2 | A |
| I _{TSM} | Non-repetitive peak on-state current | full sine wave; $T_j = 25 \degree C$ prior to surge $t = 20 \ ms$ $t = 16.7 \ ms$ | - | 95 109 | | AA |
| l²t dl _⊤ /dt | I ² t for fusing Repetitive rate of rise of on-state current after triggering | t = 10 ms $I_{TM} = 20 \text{ A}; I_G = 0.2 \text{ A};$ $dI_G/dt = 0.2 \text{ A}/\mu \text{s}$ | - | 45 | 5 | A ² s A/μs |
| I _{GM} V _{GM} P _{GM} | Peak gate current Peak gate voltage Peak gate power | | - | 2 5 5 | | A V W |
| P _{G(AV)} | Average gate power | over any 20 ms period | - | 0.5 | 5 | W |
| T _{stg} T _j | Storage temperature Operating junction temperature | | -40 - | 150 125 | | Ĵ, Ĵ, |

QUICK REFERENCE DATA

PARAMETER

voltages

current

mb

PIN CONFIGURATION

₽

2

3

1

Repetitive peak off-state

Non-repetitive peak on-state

RMŠ on-state current

SYMBOL

 V_{DRM}

T(RMS)

 I_{TSM}

¹ Although not recommended, off-state voltages up to 800V may be applied without damage, but the triac may switch to the on-state. The rate of rise of current should not exceed 15 A/us.

BTA212B series D, E and F

THERMAL RESISTANCES

| SYMBOL | PARAMETER | CONDITIONS | MIN. | TYP. | MAX. | UNIT |
|---|--|---|--------|--------------|-----------------|-------------------|
| R _{th j-mb} R _{th j-a} | Thermal resistance junction to mounting base Thermal resistance junction to ambient | full cycle half cycle in free air | - - | - - 55 | 1.5 2.0 - | K/W K/W K/W |

STATIC CHARACTERISTICS

 $T_i = 25$ °C unless otherwise stated

| SYMBOL | PARAMETER | CONDITIONS | MIN. | TYP. | | MAX. | | UNIT |
|-----------------|--|--|----------------|-------------------|----------------|-----------------|----------------|----------------|
| | | BTA212B- | | D | D | E | F | |
| I _{GT} | Gate trigger current ² | $V_{D} = 12 \text{ V}; I_{T} = 0.1 \text{ A}$ T2+G+ | - | 1.0 | 5 | 10 | 25 | mĄ |
| IL | Latching current | T2+ G- T2- G- V _D = 12 V; I _{GT} = 0.1 A | - | 2.2 3.3 | 5 5 5 | 10 10 | 25 25 | mA mA |
| 'L | | T2+ G+ T2+ G- T2- G- | - - - | 6 6 9 | 15 25 25 | 25 30 30 | 30 40 40 | mA mA mA |
| I _H | Holding current | V _D = 12 V; I _{GT} = 0.1 A | - | 3.8 | 15 | 25 | 30 | mA |
| | | | | | D, E, F | = | | |
| $V_{T} V_{GT}$ | On-state voltage Gate trigger voltage | $I_T = 17 \text{ A}$ $V_D = 12 \text{ V}; I_T = 0.1 \text{ A}$ $V_D = 400 \text{ V}; I_T = 0.1 \text{ A};$ | - - 0.25 | 1.3 0.7 0.4 | | 1.6 1.5 - | | V V V |
| I _D | Off-state leakage current | $T_{j} = 125 °C$ $V_{D} = V_{DRM(max)}$; $T_{j} = 125 °C$ | - | 0.1 | | 0.5 | | mA |

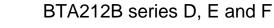
DYNAMIC CHARACTERISTICS

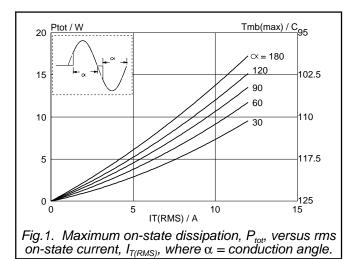
 $T_i = 25$ °C unless otherwise stated

| SYMBOL | PARAMETER | CONDITIONS | | MIN. | | TYP. | MAX. | UNIT |
|-----------------------|---|--|---------|------|----|------|------|------|
| | | BTA212B- | D | E | F | D | | |
| dV _D /dt | Critical rate of rise of off-state voltage | $V_{DM} = 67\% V_{DRM(max)};$ $T_j = 110$ °C; exponential waveform; gate open circuit | 20 | 60 | 70 | 30 | - | V/µs |
| dl _{com} /dt | Critical rate of change of commutating current | $V_{DM} = 400 \text{ V}; \text{ T}_{j} = 110 \text{ °C};$ $I_{T(RMS)} = 12 \text{ A};$ $dV_{com}/dt = 20V/\mu \text{s}; \text{ gate}$ open circuit | 1.8 | 3.5 | 5 | 3 | - | A/ms |
| dl _{com} /dt | Critical rate of change of commutating current | $V_{DM} = 400 \text{ V}; \text{ T}_{j} = 110 \text{ °C};$ $I_{T(RMS)} = 12 \text{ A};$ $dV_{com}/dt = 0.1 \text{ V}/\mu\text{s}; \text{ gate}$ open circuit | 5 | 16 | 19 | 100 | - | A/ms |
| | | | D, E, F | | | | | |
| t _{gt} | Gate controlled turn-on time | $I_{TM} = 12 \text{ A}; V_D = V_{DRM(max)};$ $I_G = 0.1 \text{ A}; dI_G/dt = 5 \text{ A/}\mu s$ | - | - | - | 2 | - | μs |

² Device does not trigger in the T2-, G+ quadrant.

Three quadrant triacs guaranteed commutation





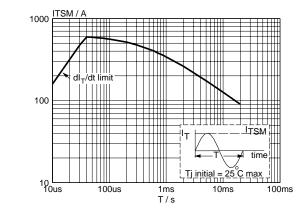
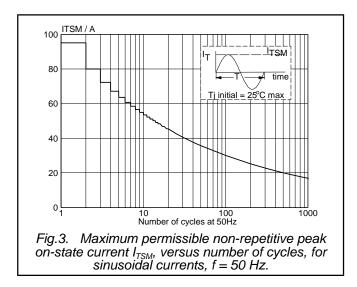
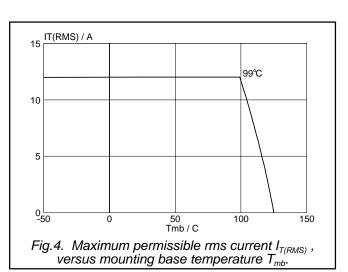


Fig.2. Maximum permissible non-repetitive peak on-state current I_{TSM} , versus pulse width t_p , for sinusoidal currents, $t_p \le 20ms$.





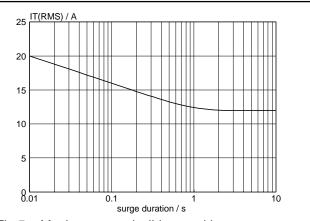
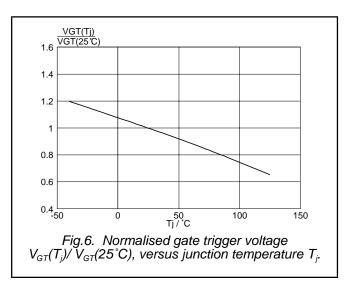
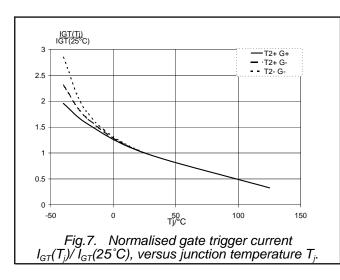


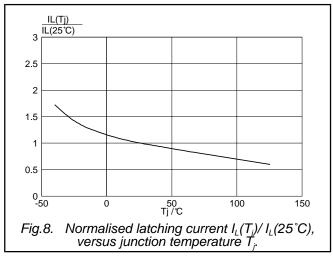
Fig.5. Maximum permissible repetitive rms on-state current $I_{T(RMS)}$, versus surge duration, for sinusoidal currents, f = 50 Hz; $T_{mb} \le 99^{\circ}C$.

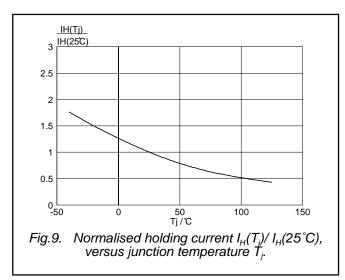


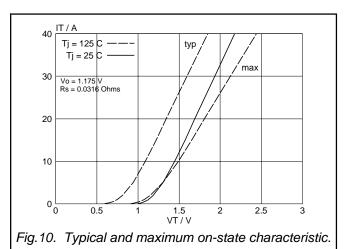
Three quadrant triacs guaranteed commutation

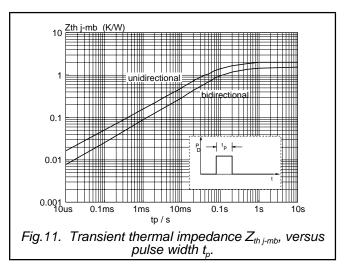
BTA212B series D, E and F

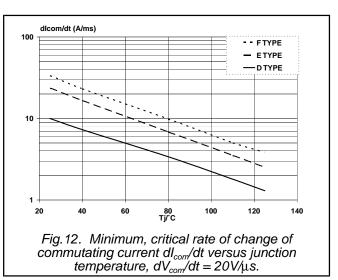








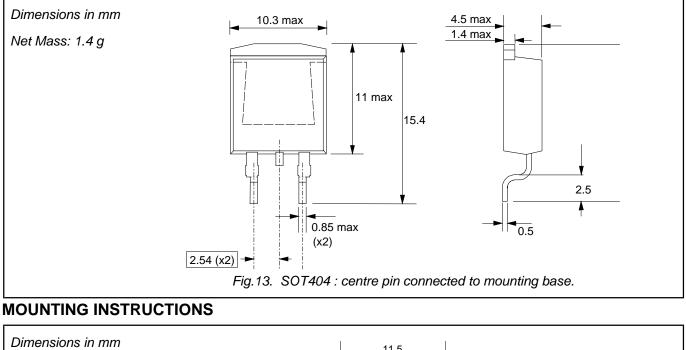


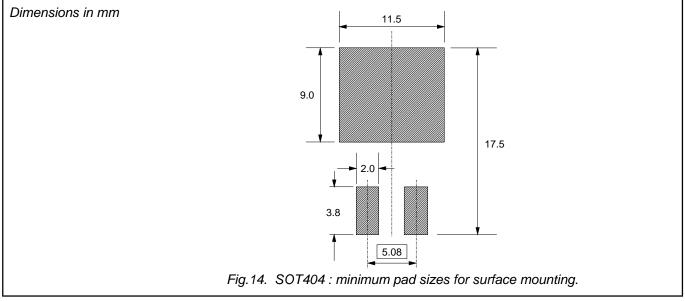


Three quadrant triacs guaranteed commutation

BTA212B series D, E and F

MECHANICAL DATA





Notes

1. Plastic meets UL94 V0 at 1/8".

Three quadrant triacs guaranteed commutation

BTA212B series D, E and F

DEFINITIONS

| Data sheet status | | | | | |
|--|---|--|--|--|--|
| Objective specification This data sheet contains target or goal specifications for product development. | | | | | |
| Preliminary specification | This data sheet contains preliminary data; supplementary data may be published later. | | | | |
| Product specification | This data sheet contains final product specifications. | | | | |
| Limiting values | | | | | |
| Limiting values are given in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of this specification is not implied. Exposure to limiting values for extended periods may affect device reliability. | | | | | |
| Application information | | | | | |
| Where application information is given, it is advisory and does not form part of the specification. | | | | | |
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